# MJE13007-M

## NPN SILICON TRANSISTOR

# NPN BIPOLAR POWER TRANSISTOR FOR SWITCHING POWER SUPPLY APPLICATIONS

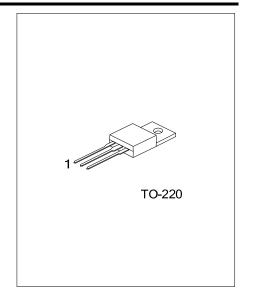
### **■** DESCRIPTION

The UTC **MJE13007-M** is designed for high-voltage and high-speed power switching inductive circuits where fall time is critical. It is particularly suited for 115 and 220 V switch mode applications.

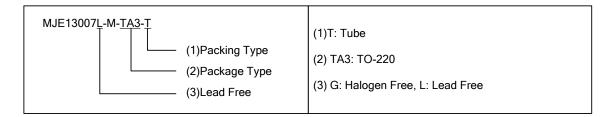
### **■ FEATURES**

- \*  $V_{\text{CEO(SUS)}}400V$
- \* 700V Blocking Capability

### **■ ORDERING INFORMATION**



	Ordering	Deelsege	Pin Assignment			Doolsing	
	Lead Free	Halogen Free	ree Package	1	2	3	Packing
I	MJE13007L-M-TA3-T	MJE13007G-M-TA3-T	TO-220	В	С	Е	Tube



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### ABSOLUTE MAXIMUM RATING

PARAMETER		SYMBOL	RATINGS	UNIT
Collector-Emitter Sustaining Voltage		$V_{CEO}$	400	V
Collector-Emitter Breakdown Voltage		$V_{CBO}$	700	V
Emitter-Base Voltage		$V_{EBO}$	9.0	V
Callagtar Current	Continuous	I <sub>C</sub>	8.0	Α
Collector Current	Peak (1)	I <sub>CM</sub>	16	Α
Base Current	Continuous	I <sub>B</sub>	4.0	Α
Base Current	Peak (1)	I <sub>BM</sub>	8.0	Α
Emitter Current	Continuous	Ι <sub>Ε</sub>	12	Α
Emiller Current	Peak (1)	I <sub>EM</sub>	24	Α
Power Dissipation $T_C = 25^{\circ}C$		$P_D$	80	W
Junction Temperature		$T_J$	+150	°C
Storage Temperature		T <sub>STG</sub>	-55~+150	°C

Note: Absolute maximum ratings are those values beyond which the device could be permanently damaged. Absolute maximum ratings are stress ratings only and functional device operation is not implied.

### **■ THERMAL DATA**

PARAMETER	SYMBOL	RATINGS	UNIT	
Junction to Ambient	$\theta_{JA}$	62.5	°C/W	
Junction to Case	$\theta_{JC}$	1.56	°C/W	

Note 1: Pulse Test: Pulse Width = 5.0 ms, Duty Cycle≤10%.

Measurement made with thermocouple contacting the bottom insulated mounting surface of the package (in a location beneath the die), the device mounted on a heatsink with thermal grease applied at a mounting torque of 6 to 8•lbs.

### ■ **ELECTRICAL CHARACTERISTICS** (T<sub>C</sub>=25°C, unless otherwise noted)

PARAMETER	SYMBOL	TEST CONDITIONS	MIN	TYP	MAX	UNIT		
Collector-Emitter Sustaining Voltage	V <sub>CEO(SUS)</sub>	I <sub>C</sub> =10mA, I <sub>B</sub> =0	400			V		
Collector Cutoff Current	I <sub>CBO</sub>	V <sub>CES</sub> =700V			0.1	mA		
Collector Cutoff Current		V <sub>CES</sub> =700V, T <sub>C</sub> =125°C			1.0	mA		
Emitter Cutoff Current	I <sub>EBO</sub> V <sub>EB</sub> =9.0V, I <sub>C</sub> =0				100	μA		
DC Current Gain	h <sub>FE1</sub>	I <sub>C</sub> =2.0A, V <sub>CE</sub> =5.0V	8.0		40			
DC Current Gain	h <sub>FE2</sub>	I <sub>C</sub> =5.0A, V <sub>CE</sub> =5.0V	5.0		30			
	V <sub>CE(SAT)</sub>	I <sub>C</sub> =2.0A, I <sub>B</sub> =0.4A			1.0	V		
		I <sub>C</sub> =5.0A, I <sub>B</sub> =1.0A			2.0			
Collector-Emitter Saturation Voltage		I <sub>C</sub> =5.0A, I <sub>B</sub> =1.0A, T <sub>C</sub> =100°C			3.0			
		I <sub>C</sub> =5.0A, I <sub>B</sub> =2.5A			0.6			
		I <sub>C</sub> =8.0A, I <sub>B</sub> =2.0A			3.0			
	V <sub>BE(SAT)</sub>	I <sub>C</sub> =2.0A, I <sub>B</sub> =0.4A			1.2	V		
Dage Emitter Caturation Voltage		I <sub>C</sub> =5.0A, I <sub>B</sub> =1.0A			1.6			
Base-Emitter Saturation Voltage		I <sub>C</sub> =5.0A, I <sub>B</sub> =1.0A, T <sub>C</sub> =100°C			1.5			
		I <sub>C</sub> =5.0A, I <sub>B</sub> =2.5A		1.2	1.5			
Current-Gain-Bandwidth Product	f⊤	I <sub>C</sub> =500mA, V <sub>CE</sub> =10V, f=1.0 MHz	4.0	14		MHz		
Output Capacitance	C <sub>OB</sub>	V <sub>CB</sub> =10V, I <sub>E</sub> =0, f=0.1MHz		80		pF		
RESISTIVE LOAD (TABLE 1)								
Delay Time	$t_D$	\\ -405\\ I =5.0A		0.025	0.1	μs		
Rise Time	$t_R$	V <sub>CC</sub> =125V, I <sub>C</sub> =5.0A,		0.5	1.5	μs		
Storage Time	t <sub>S</sub>	I <sub>B1</sub> =I <sub>B2</sub> =1.0A, t <sub>P</sub> =25µs,		1.8	3.0	μs		
Fall Time	t <sub>F</sub>	Duty Cycle≤1.0%		0.23	0.7	μs		

Note: Pulse Test: Pulse Width≤300µs, Duty Cycle≤2.0%



### ■ TYPICAL THERMAL RESPONSE

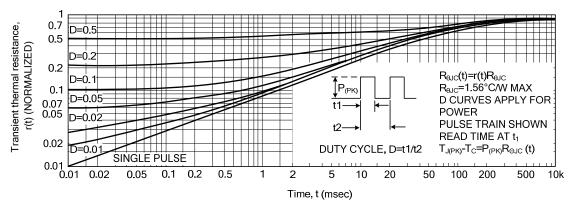


Fig. 1 Typical Thermal Response

There are two limitations on the power handling ability of a transistor: average junction temperature and second breakdown. Safe operating area curves indicate  $I_{C^-}V_{CE}$  limits of the transistor that must be observed for reliable operation; i.e., the transistor must not be subjected to greater dissipation than the curves indicate.

The data of Fig. 7 is based on  $T_C$  = 25°C;  $T_{J(PK)}$  is variable depending on power level. Second breakdown pulse limits are valid for duty cycles to 10% but must be debated when  $T_C \ge 25$ °C. Second breakdown limitations do not debate the same as thermal limitations. Allowable current at the voltages shown on Fig. 7 may be found at any case temperature by using the appropriate curve on Fig. 9.

At high case temperatures, thermal limitations will reduce the power that can be handled to values less than the limitations imposed by second breakdown.

Use of reverse biased safe operating area data (Fig. 8) is discussed in the applications information section.

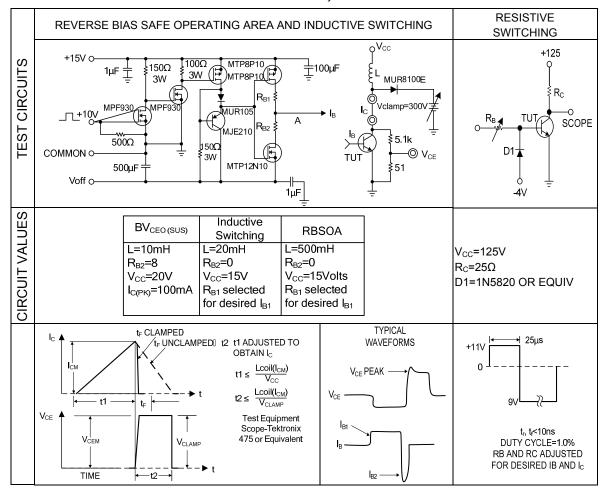


Table 1. Test Conditions for Dynamic Performance

### TYPICAL CHARACTERISTICS

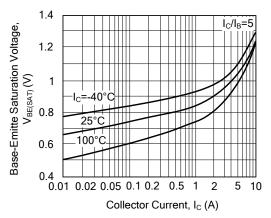


Fig. 2 Base-Emitter Saturation Voltage

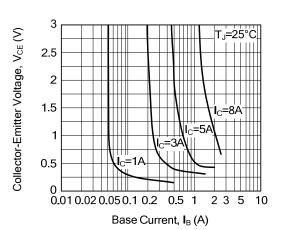


Fig. 4 Collector Saturation Region

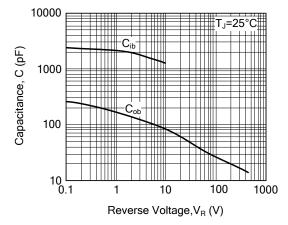


Fig. 6 Capacitance

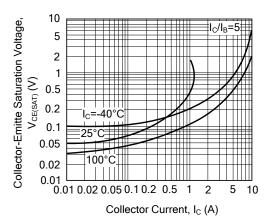


Fig. 3 Collector-Emitter Saturation Voltage

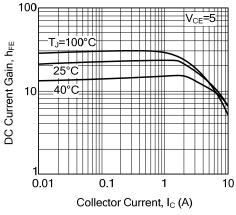


Fig. 5 DC Current Gain

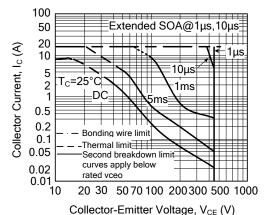


Fig. 7 Maximum Forward Bias Safe
Operating Area

### TYPICAL CHARACTERISTICS

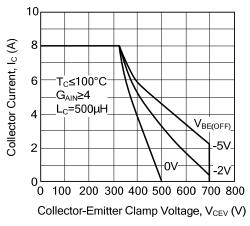


Fig. 8 Maximum Reverse Bias Switching Safe Operating Area

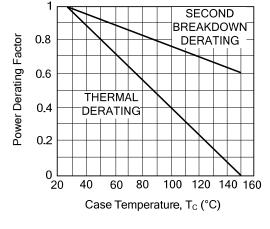


Fig. 9 Forward Bias Power Derating

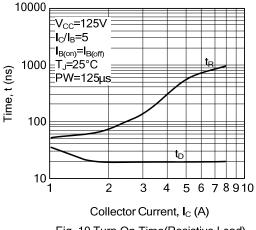


Fig. 10 Turn-On Time(Resistive Load)

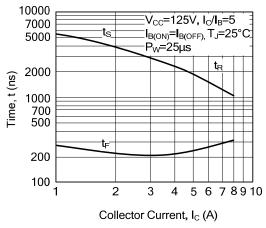


Fig. 11 Turn-Off Time(Resistive Load)

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